2SD2137, 2SD2137A

Silicon NPN triple diffusion planar type

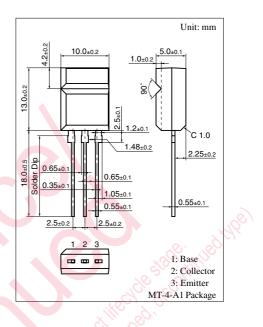
For power amplification

Complementary to 2SB1417 and 2SB1417A

Features

- \bullet High forward current transfer ratio h_{FE} which has satisfactory linearity
- \bullet Low collector to emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Allowing supply with the radial taping
- Absolute Maximum Ratings $T_C = 25^{\circ}C$

0 0					
Parameter		Symbol	Rating	Unit	
Collector to base	2SD2137	V _{CBO}	60	V	
voltage	2SD2137A		80		
Collector to	2SD2137	V _{CEO}	60	V	
emitter voltage	2SD2137A		80		
Emitter to base voltage		V_{EBO}	6	V	
Peak collector current		I _{CP}	5	А	
Collector current		I _C	3	А	
Collector power	$T_C = 25^{\circ}C$	P _C	15	W	
dissipation	$T_a = 25^{\circ}C$		2		
Junction temperature		Tj	150	°C	
Storage temperature		T _{stg}	-55 to +150	°C	



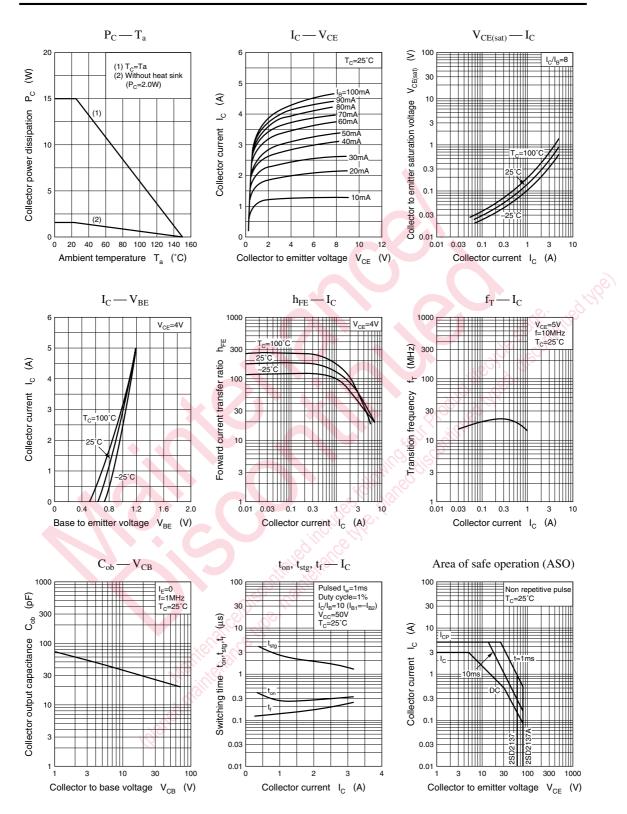
Electrical Characteristics $T_C = 25^{\circ}C$

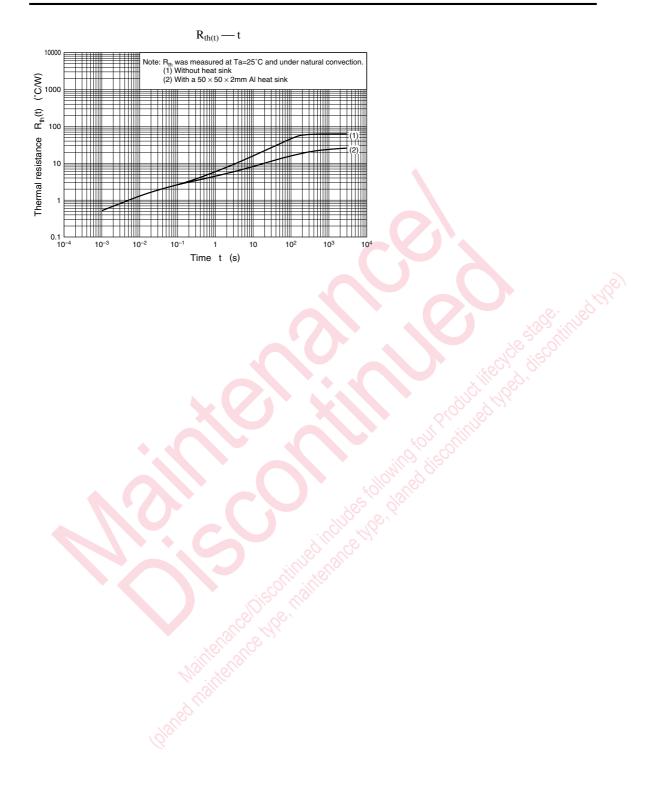
Parameter	r	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SD2137	I _{CES}	$V_{CE} = 60 \text{ V}, V_{BE} = 0$			100	μΑ
current	2SD2137A		$V_{CE} = 80 V, V_{BE} = 0$			100	
Collector cutoff	2SD2137	I _{CEO}	$V_{CE} = 30 \text{ V}, I_{B} = 0$			100	μΑ
current	2SD2137A		$V_{CE} = 60 V, I_B = 0$			100	
Emitter cutoff current		I _{EBO}	$V_{EB} = 6 V, I_C = 0$			100	μA
Collector to emitter	2SD2137	V _{CEO}	$I_{\rm C} = 30 \text{ mA}, I_{\rm B} = 0$	60			v
voltage	2SD2137A	* 0 ¹ /0		80			
Forward current transfe	er ratio	h _{FE1} *	$V_{CE} = 4 V, I_C = 1 A$	70		250	
		h _{FE2}	$V_{CE} = 4 V, I_C = 3 A$	10			
Base to emitter voltage		V _{BE}	$V_{CE} = 4 V, I_C = 3 A$			1.8	V
Collector to emitter satu	ration voltage	V _{CE(sat)}	$I_{\rm C} = 3 \text{ A}, I_{\rm B} = 0.375 \text{ A}$			1.2	v
Transition frequency	10.0.	\mathbf{f}_{T}	$V_{CE} = 5 V, I_C = 0.2 A, f = 10 MHz$		30		MHz
Turn-on time		t _{on}	$I_{C} = 1 \text{ A}, I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A},$		0.3		μs
Storage time		t _{stg}	$V_{CC} = 50 V$		2.5		μs
Fall time		t _f			0.2		μs

Note) *: Rank classification

Rank	Q	R
h _{FE1}	70 to 150	120 to 250

Ordering can be made by the common rank (PQ rank $h_{FE1} = 70$ to 250) in the rank classification.





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